NSN 5961-01-106-4655

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-106-4655 **Inclosure Material:** Plastic **Overall Length:** 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.300 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** -40.0 collector to base voltage/static/emitter open all transistor and -40.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** -1.00 amperes source cutoff current all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0